



## PI74FCT280T

### Fast CMOS

### 9-Bit Parity Generator/Checker

#### Product Features:

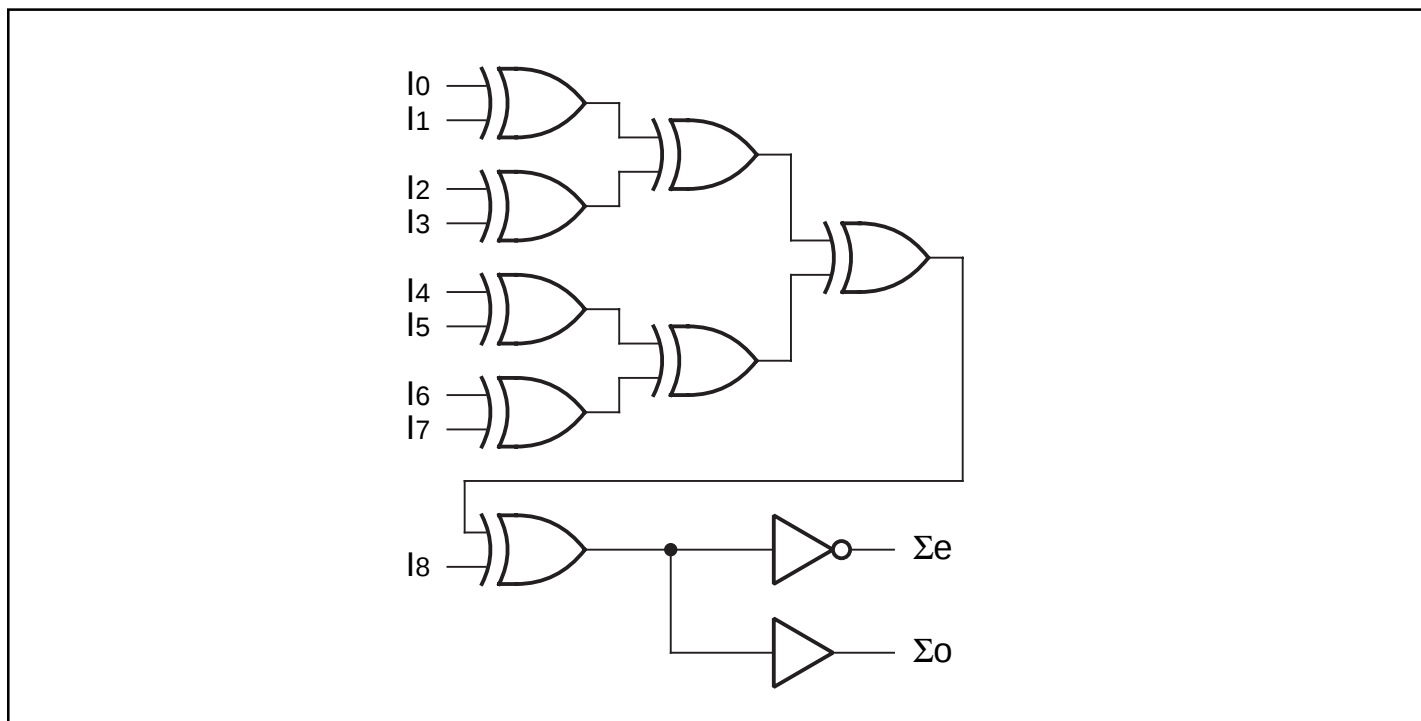
- PI74FCT280T is pin compatible with bipolar FAST™ Series at a higher speed and lower power consumption
- TTL input and output levels
- Extremely low static power
- Hysteresis on all inputs
- Industrial operating temperature range:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$
- Packages available:
  - 14-pin 150 mil wide SOIC (W)
  - 16-pin 150 mil wide QSOP (Q)

#### Product Description:

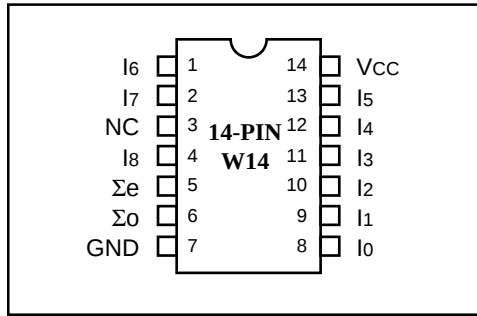
Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.8 micron CMOS technology, achieving industry leading speed grades.

The PI74FCT280T is a high-speed CMOS TTL-compatible 9-bit parity generator-checkers. Both odd and even parity outputs are available for generating or checking odd or even parity.

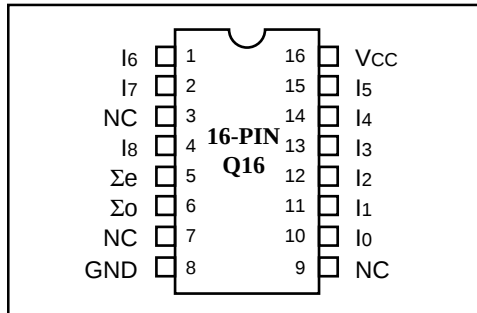
#### Logic Block Diagram



### PI74FCT280T 14-Pin SOIC Configuration



### PI74FCT280T 16-Pin QSOP Configuration



### Product Pin Description

| Pin Name | Description     |
|----------|-----------------|
| I8–I0    | Data In         |
| Σe       | Even Parity Out |
| Σo       | Odd Parity Out  |
| GND      | Ground          |
| VCC      | Power           |

### Truth Table<sup>(1)</sup>

| Function    | Inputs                                     | Outputs |    |
|-------------|--------------------------------------------|---------|----|
|             | I8–I0                                      | Σe      | Σo |
| Even Parity | No. of Bits at TTL High<br>= 0, 2, 4, 6, 8 | H       | L  |
| Odd Parity  | No. of Bits at TTL High<br>= 1, 3, 5, 7, 9 | L       | H  |

#### Note:

- H = High Voltage Level  
L = Low Voltage Level

### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

|                                                               |                 |
|---------------------------------------------------------------|-----------------|
| Storage Temperature .....                                     | –65°C to +150°C |
| Ambient Temperature with Power Applied .....                  | –40°C to +85°C  |
| Supply Voltage to Ground Potential (Inputs & Vcc Only) .....  | –0.5V to +7.0V  |
| Supply Voltage to Ground Potential (Outputs & D/O Only) ..... | –0.5V +7.0V     |
| DC Input Voltage .....                                        | –0.5V to +7.0V  |
| DC Output Current .....                                       | 120 mA          |
| Power Dissipation .....                                       | 0.5W            |

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### Capacitance (TA = 25°C, f = 1 MHz)

| Parameters <sup>(1)</sup> | Description        | Test Conditions | Typ | Max. | Units |
|---------------------------|--------------------|-----------------|-----|------|-------|
| CIN                       | Input Capacitance  | VIN = 0V        | 6   | 10   | pF    |
| COU                       | Output Capacitance | VOU = 0V        | 8   | 12   | pF    |

#### Notes:

- This parameter is determined by device characterization but is not production tested.

**DC Electrical Characteristics** (Over the Operating Range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = 5\text{V} \pm 5\%$ )

| Parameters | Description           | Test Conditions <sup>(1)</sup>                         |                            | Min | Typ <sup>(2)</sup> | Max  | Units         |
|------------|-----------------------|--------------------------------------------------------|----------------------------|-----|--------------------|------|---------------|
| $V_{OH}$   | Output HIGH Voltage   | $V_{CC} = \text{Min.}$ , $V_{IN} = V_{IH}$ or $V_{IL}$ | $I_{OH} = -15.0\text{ mA}$ | 2.4 | 3.0                |      | V             |
| $V_{OL}$   | Output LOW Current    | $V_{CC} = \text{Min.}$ , $V_{IN} = V_{IH}$ or $V_{IL}$ | $I_{OL} = 48\text{ mA}$    |     | 0.3                | 0.50 | V             |
| $V_{IH}$   | Input HIGH Voltage    | Guaranteed Logic HIGH Level                            |                            | 2.0 |                    |      | V             |
| $V_{IL}$   | Input LOW Voltage     | Guaranteed Logic LOW Level                             |                            |     |                    | 0.8  | V             |
| $I_{IH}$   | Input HIGH Current    | $V_{CC} = \text{Max.}$                                 | $V_{IN} = V_{CC}$          |     |                    | 1    | $\mu\text{A}$ |
| $I_{IL}$   | Input LOW Current     | $V_{CC} = \text{Max.}$                                 | $V_{IN} = \text{GND}$      |     |                    | -1   | $\mu\text{A}$ |
| $V_{IK}$   | Clamp Diode Voltage   | $V_{CC} = \text{Min.}$ , $I_{IN} = -18\text{ mA}$      |                            |     | -0.7               | -1.2 | V             |
| $I_{OS}$   | Short Circuit Current | $V_{CC} = \text{Max.}^{(3)}$ , $V_{OUT} = \text{GND}$  |                            | -60 | -120               |      | mA            |
| $I_{OFF}$  | Power Down Disable    | $V_{CC} = \text{GND}$ , $V_{OUT} = 4.5\text{V}$        |                            | —   | —                  | 100  | $\mu\text{A}$ |
| $V_H$      | Input Hysteresis      |                                                        |                            |     | 200                |      | mV            |

**Notes:**

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for applicable device type.
- Typical values are at  $V_{CC} = 5.0\text{V}$ ,  $+25^{\circ}\text{C}$  ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

**Switching Characteristics over Operating Range**

| Parameters     | Description                                            | Conditions <sup>(1)</sup> | 280T |      | 280AT |     | 280BT |     | 280CT |     | Unit |
|----------------|--------------------------------------------------------|---------------------------|------|------|-------|-----|-------|-----|-------|-----|------|
|                |                                                        |                           | Com. |      | Com.  |     | Com.  |     | Com.  |     |      |
|                |                                                        |                           | Min  | Max  | Min   | Max | Min   | Max | Min   | Max |      |
| tPHLE<br>tPLHE | Propagation Delay<br>I0 – I8 to $\Sigma_{\text{even}}$ | CL = 50 pF<br>RL = 500Ω   | 3.0  | 10.0 | 3.0   | 7.5 | 3.0   | 6.3 | 3.0   | 5.3 | ns   |
| tPHLO<br>tPLHO | Propagation Delay<br>I0 – I8 to $\Sigma_{\text{odd}}$  |                           | 3.0  | 10.0 | 3.0   | 7.5 | 3.0   | 6.3 | 3.0   | 5.3 | ns   |

**Notes:**

- See test circuit and waveforms.
- Minimum limits are guaranteed but not tested on Propagation Delays.

**Power Supply Characteristics**

| Parameters       | Description                                     | Test Conditions <sup>(1)</sup>                                                                                                                            |                                                            | Min. | Typ <sup>(2)</sup> | Max.                | Units      |
|------------------|-------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------|------|--------------------|---------------------|------------|
| I <sub>CC</sub>  | Quiescent Power Supply Current                  | V <sub>CC</sub> = Max.                                                                                                                                    | V <sub>IN</sub> = GND<br>or V <sub>CC</sub>                |      | 0.1                | 500                 | μA         |
| ΔI <sub>CC</sub> | Supply Current per Input @ TTL HIGH             | V <sub>CC</sub> = Max.                                                                                                                                    | V <sub>IN</sub> = 3.4V <sup>(3)</sup>                      |      |                    | 2.0                 | mA         |
| I <sub>CCD</sub> | Supply Current per Input per MHz <sup>(4)</sup> | V <sub>CC</sub> = Max.,<br>Outputs Open<br>One Input Toggling<br>50% Duty Cycle                                                                           | V <sub>IN</sub> = V <sub>CC</sub><br>V <sub>IN</sub> = GND |      |                    | 0.25                | mA/<br>MHz |
| I <sub>C</sub>   | Total Power Supply Current <sup>(6)</sup>       | V <sub>CC</sub> = Max.,<br>Outputs Open<br>f <sub>CP</sub> = 10 MHz<br>50% Duty Cycle<br>f <sub>I</sub> = 5 MHz<br>One Bit Toggling                       | V <sub>IN</sub> = V <sub>CC</sub><br>V <sub>IN</sub> = GND |      | 1.7                | 4.0 <sup>(5)</sup>  | mA         |
|                  |                                                 |                                                                                                                                                           | V <sub>IN</sub> = 3.4V<br>V <sub>IN</sub> = GND            |      | 2.2                | 6.0 <sup>(5)</sup>  |            |
|                  |                                                 | V <sub>CC</sub> = Max.,<br>Outputs Open<br>f <sub>CP</sub> = 10 MHz<br>50% Duty Cycle<br>Nine Bits Toggling<br>f <sub>I</sub> = 2.5 MHz<br>50% Duty Cycle | V <sub>IN</sub> = V <sub>CC</sub><br>V <sub>IN</sub> = GND |      | 4.0                | 7.8 <sup>(5)</sup>  |            |
|                  |                                                 |                                                                                                                                                           | V <sub>IN</sub> = 3.4V<br>V <sub>IN</sub> = GND            |      | 6.2                | 16.8 <sup>(5)</sup> |            |

**Notes:**

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V<sub>CC</sub> = 5.0V, +25°C ambient.
- Per TTL driven input (V<sub>IN</sub> = 3.4V); all other inputs at V<sub>CC</sub> or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are guaranteed but not tested.
- I<sub>C</sub> = I<sub>QUIESCENT</sub> + I<sub>INPUTS</sub> + I<sub>DYNAMIC</sub>  

$$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$$
I<sub>CC</sub> = Quiescent Current  
ΔI<sub>CC</sub> = Power Supply Current for a TTL High Input (V<sub>IN</sub> = 3.4V)  
D<sub>H</sub> = Duty Cycle for TTL Inputs High  
N<sub>T</sub> = Number of TTL Inputs at D<sub>H</sub>  
I<sub>CCD</sub> = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)  
f<sub>CP</sub> = Clock Frequency for Register Devices (Zero for Non-Register Devices)  
f<sub>I</sub> = Input Frequency  
N<sub>I</sub> = Number of Inputs at f<sub>I</sub>  
All currents are in milliamps and all frequencies are in megahertz.